

RoHS

Specification

SSC-SZR05A0A

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SEOUL SEMICONDUCTOR

SZR05A0A

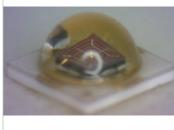
Description

The Z-Power series is designed for high current operation and high flux output applications.

It incorporates state of the art SMD

design and low thermal resistant material.

The Z Power LED is ideal light sources for general illumination applications, custom designed solutions, large backlights and high performance torches.





Features

- Super high Flux output and high Luminance
- Designed for high current operation
- SMT solderable
- Lead Free product
- RoHS compliant

Applications

- General Torch
- Architectural lighting
- Projector light source
- Traffic signals
- Task lighting
- Decorative / Pathway lighting
- Remote / Solar powered lighting
- Automotive interior / exterior lighting
- Automotive signal
 / forward lighting

* The appearance and specifications of the product can be changed for improvement without notice.

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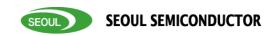
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1. Full code of Z5 series

Full code form : $X_1 X_2 X_3 X_4 X_5 X_6 X_7 X_8$

1. Part Number

X ₁	Company
X ₂	Z-Power LED series number
X ₃ X ₄	Color Specification
RO	Red
X ₅	PKG Series
5	Z5 series
X ₆	Lens type
X ₇	РСВ Туре

2. Internal Number

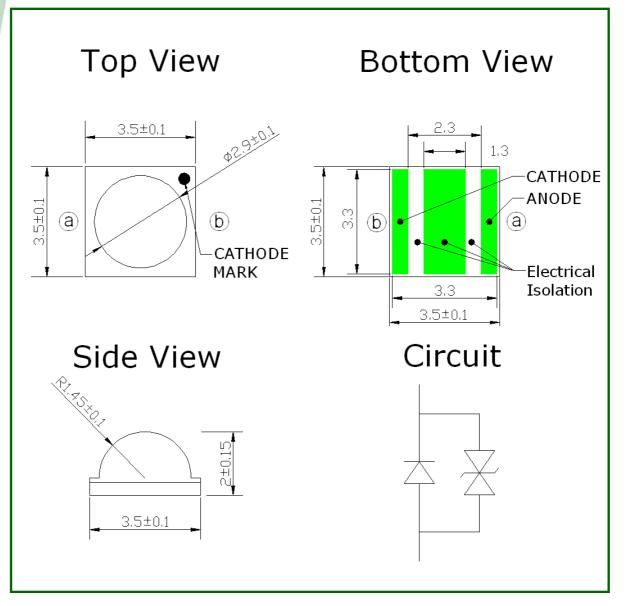
X ₈	Revision No.





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2. Outline dimensions



Notes :

- [1] All dimensions are in millimeters.
- [2] Scale : none
- [3] Undefined tolerance is ± 0.1 mm

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3. Characteristics of SZR05A0A (Red)

Red

1-1 Electro-Optical chara	(Ta=25℃, RH30%)					
Parameter	Symbol	Value			11	
Parameter		Min	Тур	Max	Unit	
Luminous Flux ^[1]	Φ _V ^[2]	41.5	55	60	lm	
	Ф _V (Тј=100℃)	-	26	-		
Dominant Wavelength ^[3]	λ _D	618	625	632	nm	
Forward Voltage [4]	V _F	-	2.4	3.0	V	
Thermal resistance (J to S)	R⊖ _{J-S}	7.0		K/W		
View Angle	2⊖ 1⁄₂	123		deg.		

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	700	mA
Reverse Voltage	V _r	5	V
Power Dissipation	P _d	2.3	W
Junction Temperature	Т _ј	125(@ I _F ≤ 700mA)	٥C
Operating Temperature	T _{opr}	-40 ~ +100	٥C
Storage Temperature	T _{stg}	-40 ~ +100	٥C
ESD Sensitivity(HBM) [6]	_	2	kV

*Notes :

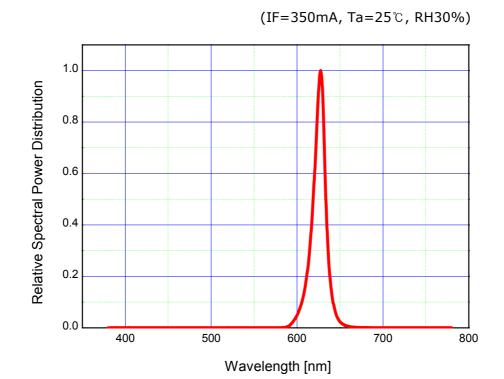
- [1] SSC maintains a tolerance of $\pm 7\%$ on flux and power measurements.
- [2] Φ_V is the total luminous flux output as measured with an integrating sphere.
- [3] Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. Color coordinate : ± 0.005 , CCT $\pm 5\%$ tolerance.
- [4] Tolerance is $\pm 0.06V$ on forward voltage measurements
- [5] A zener diode is included to protect the product from ESD.
- [6] Tolerance is ± 2.0 on CRI measurements

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4. Characteristic diagrams

Color Spectrum

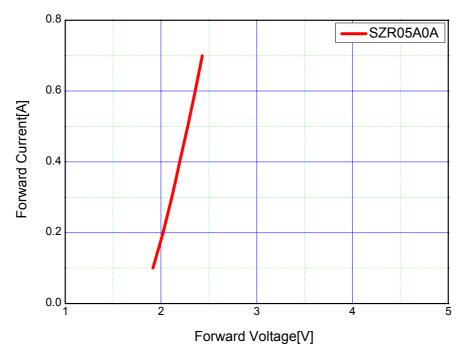




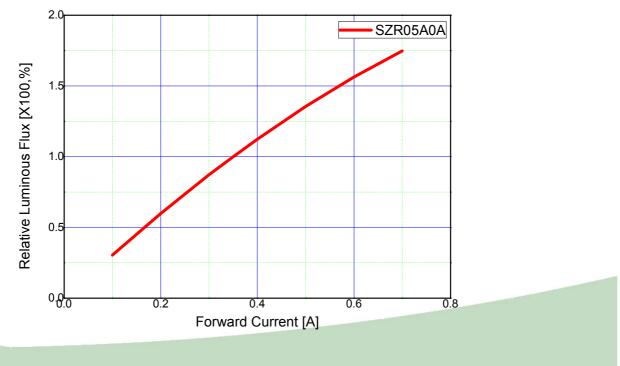


Forward Current Characteristics

Forward Voltage vs. Forward Current, Ta=25℃



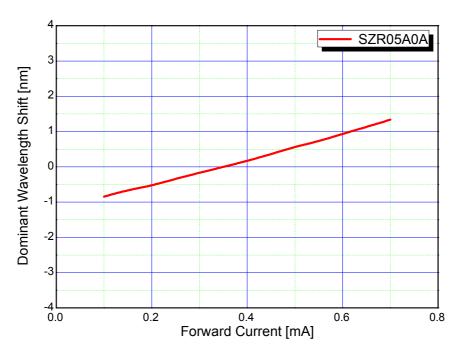
Forward Current vs. Normalized Relative Luminous Flux, Ta=25°C



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Forward Current vs Wavelength Shift, Ta=25℃

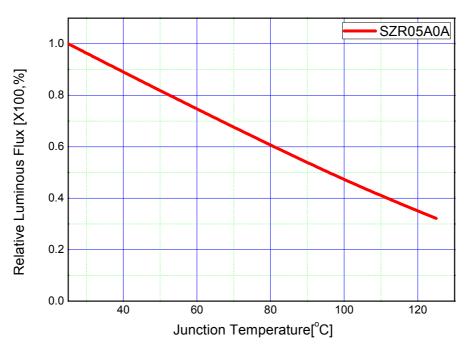
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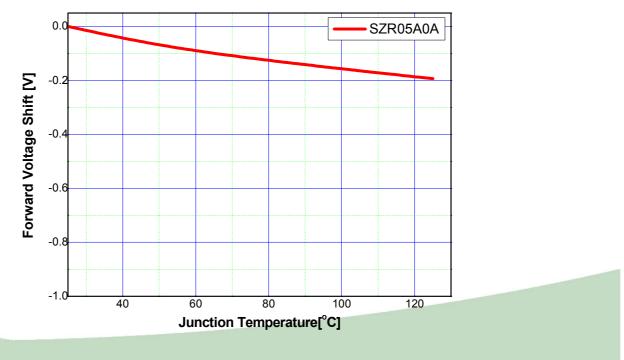


Junction Temperature Characteristics

Junction Temperature vs. Relative Light Output at IF=350mA





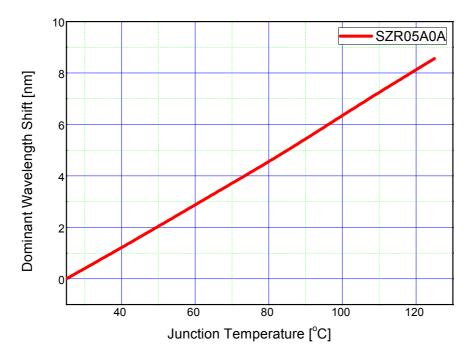


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Junction Temperature Characteristics

Junction Temperature vs. Dominant Wavelength at IF=350mA



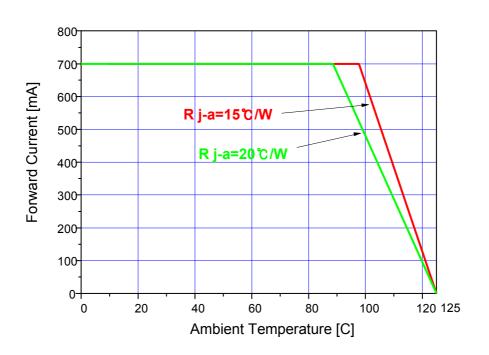


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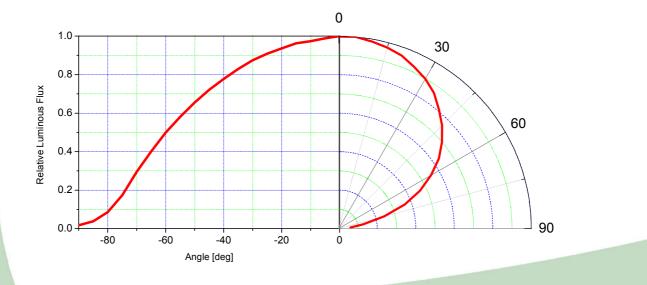


Characteristic diagrams

Ambient Temperature vs. Allowable Forward Current (Tjmax = 125°C, @0.7A)



Radiation pattern at 350mA



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5. Bin Code Description

Bin Code									
	Radiant Power (mW)Dominant Wavelength (nm)@ $I_F = 350 \text{mA}$ @ $I_F = 350 \text{mA}$		Forward Voltage (V) @ I _F = 350mA						
	R			RR1			E		
	nt Powei) I _F = 350r			Dominant Wavelength (nm) @ I _F = 350mA		Forward Voltage (V) @ I _F = 350mA			
Bin Code	Min.	Max.	Bin Code	Min.	Max.	Bin Code	Min.	Max.	
R	41.5	54.0	RR1	618	625	D	2.00	2.25	
S	54.0	70.0	RR2	625	632	E	2.25	2.50	
						F	2.50	2.75	

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6. Labeling

Rank :	$X_{10}X_{11}X_{12}X_{13}$
Quantity: 1000	
Lot No : #####	¥###########
SSC PART NUM	BER : SZR05A0A
SEOUL SZR	R05A0A

Full code form

<u>X1X2X3X4X5X6X7X8</u>

- X 1	: Company
-X ₂	: Z-Power LED series number
$-X_{3}X_{4}$: Color Specification
-X ₅	: PKG Series
- X ₆	: Lens Type
-X ₇	: РСВ Туре
-X ₈	: Revision No.

Rank

<u>X10X11X12X13</u>

-X₁₀ : Luminous Flux : LF [Im]

- $X_{11}X_{12}$: Dominant Wavelength [nm]

-X₁₃ : Forward Voltage : V_F [V]

Lot No

#1#2#3#4#5#6 - #7#8#9#10 - #11#12#13

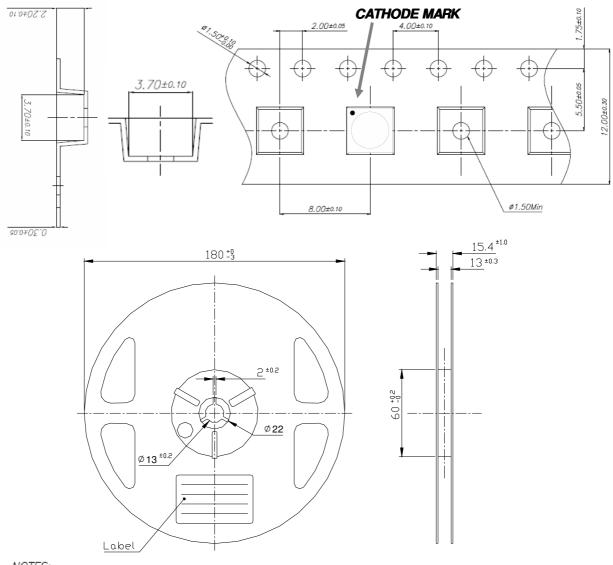
- # ₁ # ₂	: Year	$-\#_7 \#_8 \#_9 \#_{10}$: Mass order
- # ₃ # ₄	: Month	- # ₁₁ # ₁₂ # ₁₃	: Tray No.
- # ₅ # ₆	: Day		

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7. Packing



NOTES:

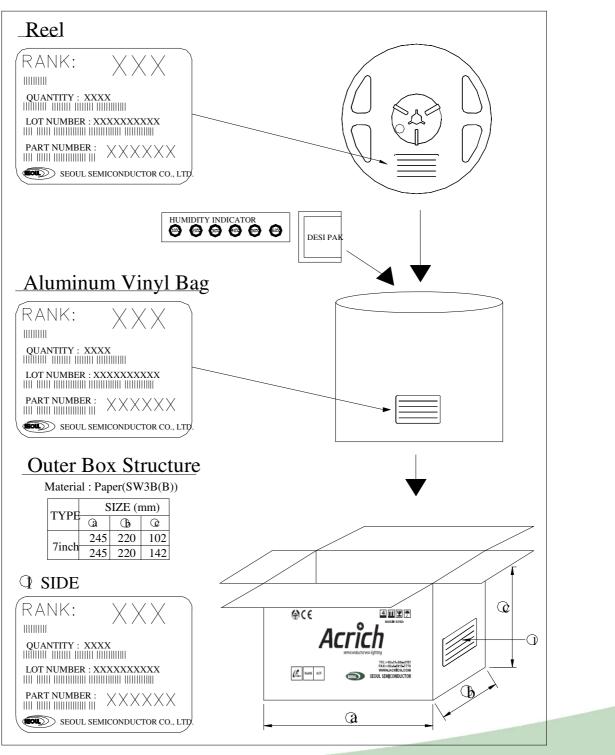
- 1. 10 sprocket hole pitch cumulative tolerance ±0.20
- 2. Camber not to exceed 1mm in 250mm
- 3. Material: Black conductive Polystyrene
- Ao and Bo measured on a plane 0.3mm above the bottom of the pocket
- Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
- Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.
- Pocket center and pocket hole center must be same position.

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7. Packing

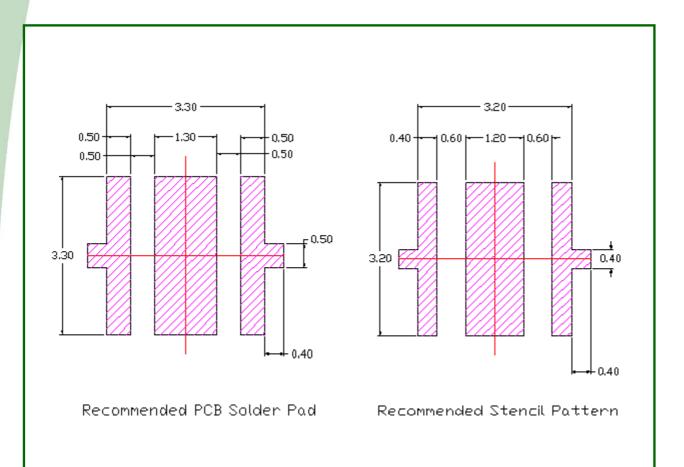


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8. Recommended solder pad



Notes :

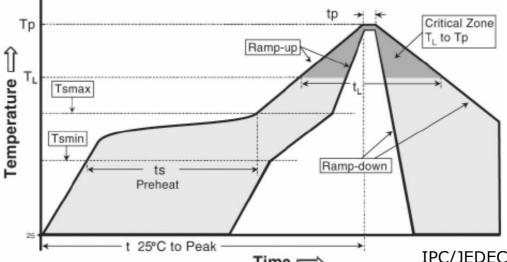
- [1] All dimensions are in millimeters.
- [2] Scale : none
- [3] This drawing without tolerances are for reference only
- [4] Undefined tolerance is ± 0.1mm

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9. Soldering



Time 📼

IPC/JEDEC J-STD-020

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (Tsmax to Tp)	3° C/second max.	3° C/second max.
Preheat - Temperature Min (Tsmin) - Temperature Max (Tsmax) - Time (Tsmin to Tsmax) (ts)	100 ℃ 150 ℃ 60-120 seconds	150 ℃ 200 ℃ 60-180 seconds
Time maintained above: - Temperature (TL) - Time (tL)	183 ℃ 60-150 seconds	217 ℃ 60-150 seconds
Peak Temperature (Tp)	215℃	260 ℃
Time within 5℃ of actual Peak Temperature (tp)2	10-30 seconds	20-40 seconds
Ramp-down Rate	6 ℃/second max.	6 ℃/second max.
Time 25 $^{\circ}$ to Peak Temperature	6 minutes max.	8 minutes max.

* Caution

1. Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.

- 2. Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
- 3. Die slug is to be soldered.
- 4. When soldering, do not put stress on the LEDs during heating.
- 5. After soldering, do not warp the circuit board.

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10. Precaution for use

(1) Storage

To avoid the moisture penetration, we recommend storing Z5 Series (Z Power) LEDs in a dry box with a desiccant . The recommended storage temperature range is 5° to 30° and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use proper SMD techniques when the LED is to be soldered dipped as separation of the lens may affect the light output efficiency. Pay attention to the following:

- a. Recommend conditions after opening the package
 - Sealing
 - Temperature : 5 ~ 40 $^{\circ}$ Humidity : less than RH30%
- b. If the package has been opened more than 1 year (MSL 2) or the color of the desiccant changes, components should be dried for 10-12hr at $60\pm5\,^\circ\!\!C$
- (3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.
- (4) Do not rapidly cool device after soldering.
- (5) Components should not be mounted on warped (non coplanar) portion of PCB.
- (6) Radioactive exposure is not considered for the products listed here in.
- (7) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.
- (8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.
- (9) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.
- (10) LEDs must be stored properly to maintain the device. If the LEDs are stored for 3 months or more after being shipped from SSC, a sealed container with a nitrogen atmosphere should be used for storage.
- (11) The appearance and specifications of the product may be modified for improvement without notice.
- (12) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.

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10. Precaution for use

- (13) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.
- (14) The slug is isolated from anode electrically.

Therefore, we recommend that you don't isolate the heat sink.

- (15) Attaching LEDs, do not use adhesives that outgas organic vapor.
- (16) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.

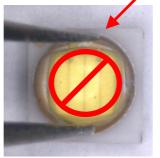


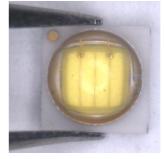




11. Handling of Silicone Resin LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.





- (2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.
- (3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.
- (4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust. As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.
- (5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin. Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.
- (6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this product with acid or sulfur material in sealed space.
- (7) Avoid leaving fingerprints on silicone resin parts.